

### NCE N-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE3400X uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.

### **General Features**

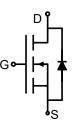
•  $V_{DS} = 30V, I_D = 5.1A$ 

 $R_{DS(ON)} < 55 \text{m}\Omega$  @  $V_{GS}$ =2.5V

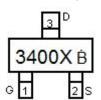
 $R_{DS(ON)}$  < 39m $\Omega$  @  $V_{GS}$ =4.5V

 $R_{DS(ON)}$  < 33m $\Omega$  @  $V_{GS}$ =10V

- High power and current handing capability
- Lead free product is acquired
- Surface mount package
- PWM applications
- Load switch
- Power management



Schematic diagram



Marking and pin assignment



SOT-23 top view

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3400X B	NCE3400X	SOT-23	Ø180mm	8 mm	3000 units

## Absolute Maximum Ratings (T<sub>A</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	30	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	I <sub>D</sub>	5.1	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	20	А
Maximum Power Dissipation	P <sub>D</sub>	1.3	W
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	°C

### **Thermal Characteristic**

ermal Resistance,Junction-to-Ambient (Note 2)	R <sub>0JA</sub>	96	°C/W
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### **Electrical Characteristics (T<sub>A</sub>=25 ℃ unless otherwise noted)**

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	30	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V	-	-	1	μΑ



## http://www.ncepower.com

# NCE3400X

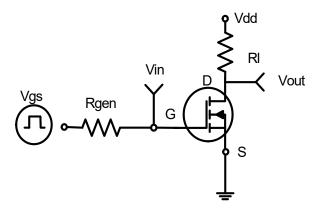
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	0.7	0.9	1.2	V
	R <sub>DS(ON)</sub>	V <sub>GS</sub> =2.5V, I <sub>D</sub> =3A	-	33	55	mΩ
Drain-Source On-State Resistance		V <sub>GS</sub> =4.5V, I <sub>D</sub> =4A	-	26	39	mΩ
		V <sub>GS</sub> =10V, I <sub>D</sub> =5A	-	24	33	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =5A	-	10	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C <sub>lss</sub>	\\ 45\\\\ 0\\	-	595	-	PF
Output Capacitance	C <sub>oss</sub>	V <sub>DS</sub> =15V,V <sub>GS</sub> =0V,	-	39	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	36	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	3.0	-	nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =15V, R <sub>L</sub> =3Ω	-	4.5	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10V, $R_{GEN}$ =3 $\Omega$	-	25	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	3.8	-	nS
Total Gate Charge	Qg	14 45)(1 54	-	9.3	-	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =15V,I <sub>D</sub> =5A, V <sub>GS</sub> =4.5V	-	1.6	-	nC
Gate-Drain Charge	Q <sub>gd</sub>		-	2.1	-	nC
Drain-Source Diode Characteristics	•	1	1	1		
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =5A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	5.1	Α

### Notes:

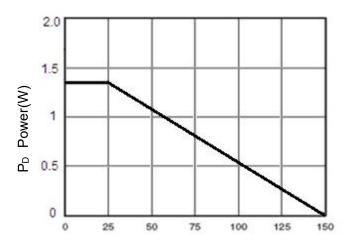
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- **3.** Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production



## **Typical Electrical and Thermal Characteristics**

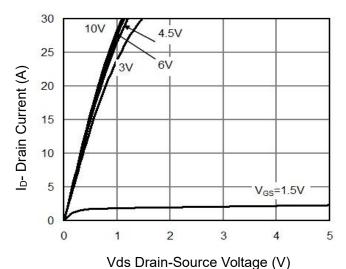


**Figure 1:Switching Test Circuit** 



T<sub>J</sub>-Junction Temperature(°C)

**Figure 3 Power Dissipation** 



**Figure 5 Output Characteristics** 

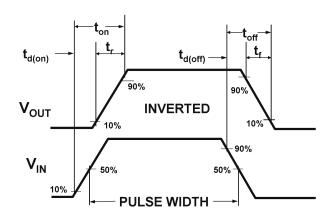
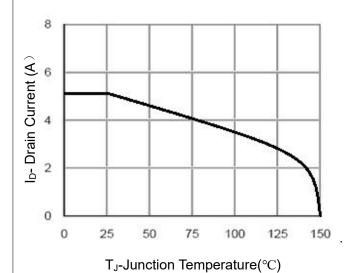


Figure 2:Switching Waveforms



**Figure 4 Drain Current** 

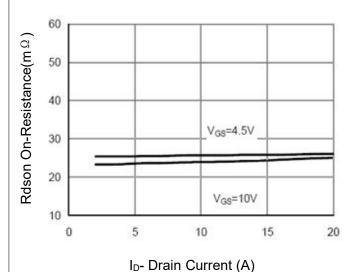
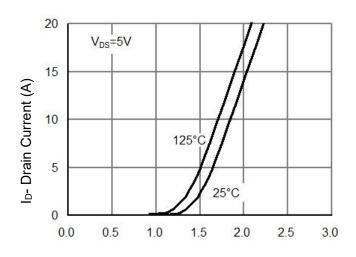
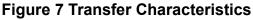


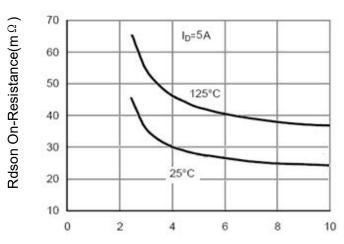
Figure 6 Drain-Source On-Resistance





Vgs Gate-Source Voltage (V)





Vgs Gate-Source Voltage (V)

## Figure 9 Rdson vs Vgs

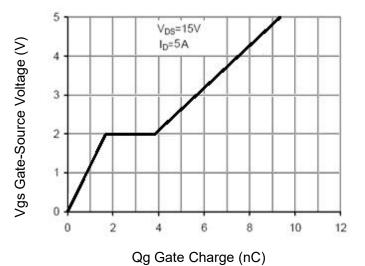
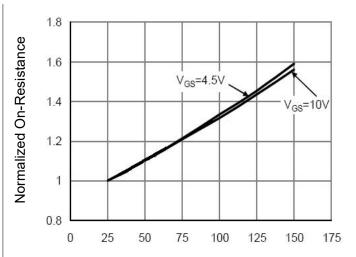
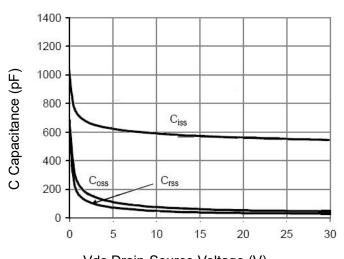


Figure 11 Gate Charge



T<sub>J</sub>-Junction Temperature(°C)

## Figure 8 Drain-Source On-Resistance



Vds Drain-Source Voltage (V)

### Figure 10 Capacitance vs Vds

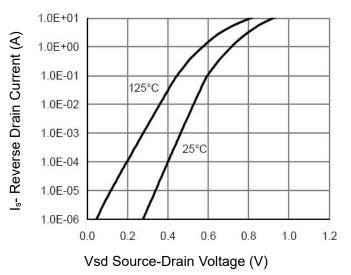
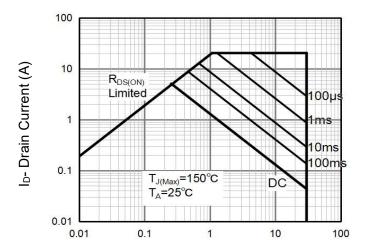


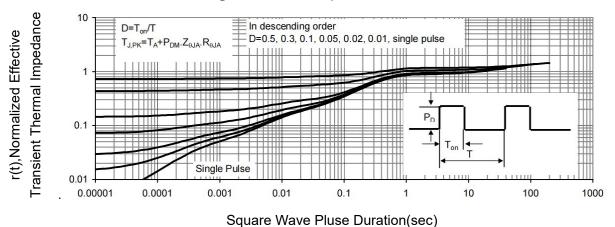
Figure 12 Source- Drain Diode Forward





Vds Drain-Source Voltage (V)

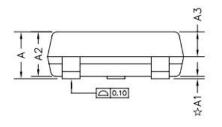
Figure 13 Safe Operation Area

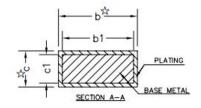


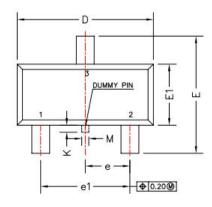
**Figure 14 Normalized Maximum Transient Thermal Impedance** 

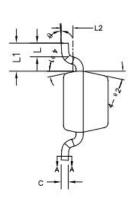


## **SOT-23 Package Information**









Complete	Millimeters			
Symbol	Min.	Max.		
Α	0.89	1.12		
A1	0.01	0.10		
A2	0.88	1.02		
A3	0.43	0.63		
b	0.36	0.50		
b1	0.35	0.45		
С	0.14	0.20		
c1	0.14	0.16		
D	2.80	3.00		
E	2.35	2.64		
E1	1.20	1.40		
е	0.90	1.00		
e1	1.80	2.00		
L	0.40	0.60		
L1	0.6REF			
L2	0.25BSC			
М	0.10	0.25		
K	0.00	0.25		
θ	0°	8°		
θ1	10°	14°		
θ2	10°	14°		



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